

■ Features

- Inverted output type (totem pole output)
- Truth Table Guaranteed: VCC from 4.5V to 30V
- Performance Specified for Common IPM Applications Over Industrial Temperature Range.
- Short Maximum Propagation Delays
- Minimized Pulse Width Distortion (PWD)
- Very High Common Mode Rejection (CMR)
- Hysteresis
- Available in Stretched SO-6 Package
- MSL class 1
- Regulatory Approvals
 - UL UL1577
 - VDE EN60747-5-5
 - CQC GB4943.1-2011

Description

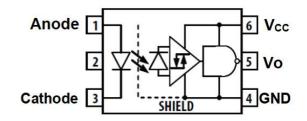
The MPH481 series fast speed photocoupler contains a LED and photo detector with built-in Schmitt trigger to provide logic-compatible waveforms, eliminating the need for additional wave shaping. The totem pole output eliminates the need for a pull up resistor and allows for direct drive Intelligent Power Module or gate drive.

Minimized propagation delay difference between devices makes these optocouplers excellent solutions for improving inverter efficiency through reduced switching dead time.

Applications

- IPM Interface Isolation
- Isolated IGBT/Power MOSFET gate drive
- Industrial Inverter
- AC and Brushless DC motor drives
- General Digital Isolation

Schematic





TURTH TABLE			
LED	OUT		
ON	Low		
OFF	High		

Note: A 0.1µF bypass capacitor must be connected between Pin 4 and 6.

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	MIN.	MAX.	UNIT	NOTE
Average Forward Current	l _F	-	20	mA	
Reverse Input Voltage	V _R	-	5	V	
Total Package Power Dissipation	P _T	-	145	mW	
Supply Voltage	Vcc	0	35	V	
Output Voltage	Vo	-0.5	Vcc	V	
Output Collector Current	Io	-	50	mA	
Isolation Voltage	Viso	5000	-	Vrms	
Operating Temperature	Topr	-40	110	°C	
Output IC Junction Temperature	TJ	-	125	°C	
Storage Temperature	Tstg	-55	125	°C	
Soldering Temperature	Tsol	-	260	°C	

Note: A ceramic capacitor $(0.1 \, \mu F)$ should be connected between pin 6 and pin 4 to stabilize the operation of a high gain linear amplifier. Otherwise, this Photocoupler may not switch properly. The bypass capacitor should be placed within 1 cm of each pin.

RECOMMENDED OPERATION CONDITIONS				
PARAMETER	SYMBOL	MIN.	MAX.	UNIT
Operating Temperature	T _A	-40	110	°C
Supply Voltage ¹	Vcc	4.5	30	V
Input Current(ON) ²	I _{F(ON)}	1.6	5	mA
Input Voltage(OFF)	V _{F(OFF)}	-	0.8	V

Note 1: Detector requires a V_{CC} of 4.5 V or higher for stable operation as output might be unstable if V_{CC} is lower than 4.5 V. Be sure to check the power ON/OFF operation other than the supply current.

Note 2: The initial switching threshold is 1.6 mA or less. It is recommended that 2.2 mA be used to permit at least a 20% LED degradation guard band.



EL	ELECTRICAL OPTICAL CHARACTERISTICS						
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITION	NOTE
	INPUT CHARACTERISTICS						
Forward Voltage	V _F	1.6	2.0	2.4	V	I _F =10mA	
Input Forward Voltage Temperature Coefficient	$\Delta V_F / \Delta T$	-	-1.237	-	mV/°C	I _F =10mA	
Input Reverse Voltage	BV_R	5	-	-	V	I _R =10µA	
Input Threshold Current (Low to High)	I _{FLH}	-	0.25	1.5	mA	V _{CC} =30V,V _O >5V	
Input Threshold Voltage (High to Low)	V _{FHL}	0.8	-	-	V	V _{CC} =30V,V _O <5V	
Input Capacitance	C _{IN}	-	60	-	pF	V _F =0, f=1kHz	2
	0	UTPUT	Γ CHAR	RACTE	RISTIC	S	
High Level		-	-	3.0	mA	V _{CC} =5.5V,V _F =0V,I _O =0mA	
Supply Current	Іссн	-	1.9	3.0	mA	V _{CC} =30V,V _F =0V,I _O =0mA	
Low Level	I _{CCL}	_	-	3.0	mA	V_{CC} =5.5 V , I_F =5 mA , I_O =0 mA	
Supply Current	ICCL	-	2.0	3.0	mA	V_{CC} =30V, I_F =5mA, I_O =0mA	
High Level	Іон	-	-	-160	mA	V_{CC} =5.5V, V_F =0V, V_O =GND	_ ₁
Output Current	IOH			-200	mA	V _{CC} =20V,V _F =0V,V _O =GND	'
Low Level	1-	160	-	-	mA	V _O =V _{CC} =5.5V,I _F =5mA	1
Output Current	l _{OL}	200	-	-	mA	V _O =V _{CC} =20V,I _F =5mA	I
High Level Output Voltage	V _{OH}	V _{CC} -	V _{CC} -	-	V	I _{OL} =-6.5mA	
Low Level Output Voltage	V _{OL}	-	0.09	0.5	V	I _{OL} =6.5mA	

Specified over recommended temperature (T_A = -40°C to +110°C, +4.5V \leq V_{CC} \leq 30V), I_{F(ON)} = 1.6mA to 5mA, V_{F(OFF)} = 0V to 0.8V, unless otherwise specified. All typicals at T_A = 25°C.

Note 1: Duration of output short circuit time should not exceed 500 μs .

Note 2: Input capacitance is measured between pin 1 and pin 3.



SWITCHING SPECIFICATION							
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITION	NOTE
	SWITCHING CHARACTERISTICS						
Propagation Delay Time to Output Low Level	t _{PHL}	-	90	220	ns		1
Propagation Delay Time to Output High Level	t _{PLH}	-	110	220	ns	f=10kHz,	1
Pulse Width Distortion	PWD	-	20	120	ns	Duty Cycle=50%,	2
Propagation Delay Difference Between Any Two Parts	PDD (t _{PHL} -t _{PLH})	-200	-	+200	ns	I _F =2mA, V _{CC} =30V	3
Rise Time	t _r	-	6	-	ns		
Fall Time	t _f	-	7	-	ns		
Common Mode Transient Immunity at Logic High	СМн	20	-	-	kV/µs	$V_F=0V,V_{CC}=5V,$ $T_A=25^{\circ}C,$ $V_{CM}=1.5kV$	4
Common Mode Transient Immunity at Logic Low	CML	20	-	-	kV/μs	I _F =4mA,V _{CC} =5V, T _A =25°C, V _{CM} =1.5kV	4

Over recommended operating conditions T_A = -40° C to 105° C, V_{CC} = +4.5 V to 30 V, $I_{F(ON)}$ = 1.6 mA to 5 mA, $V_{F(OFF)}$ = 0 V to 0.8 V,unless otherwise specified. All typicals at T_A = 25°C.

Note 1: The tPLH propagation delay is measured from the 50% point on the leading edge of the input pulse to the 1.3 V point on the leading edge of the output pulse. The tPHL propagation delay is measured from the 50% point on the trailing edge of the input pulse to the 1.3 V point on the trailing edge of the output pulse.

Note 2: Pulse Width Distortion (PWD) is defined as |tPHL - tPLH | for any given device.

Note 3: The difference of tPLH and tPHL between any two devices under the same test condition.

Note 4: CMH is the maximum slew rate of the common mode voltage that can be sustained with the output voltage in the logic high state, $V_0 > 2.0$ V. CML is the maximum slew rate of the common mode voltage that can be sustained with the output voltage in the logic low state, $V_0 < 0.8$ V. Note: Equal value split resistors (Rin/2) must be used at both ends of the LED.

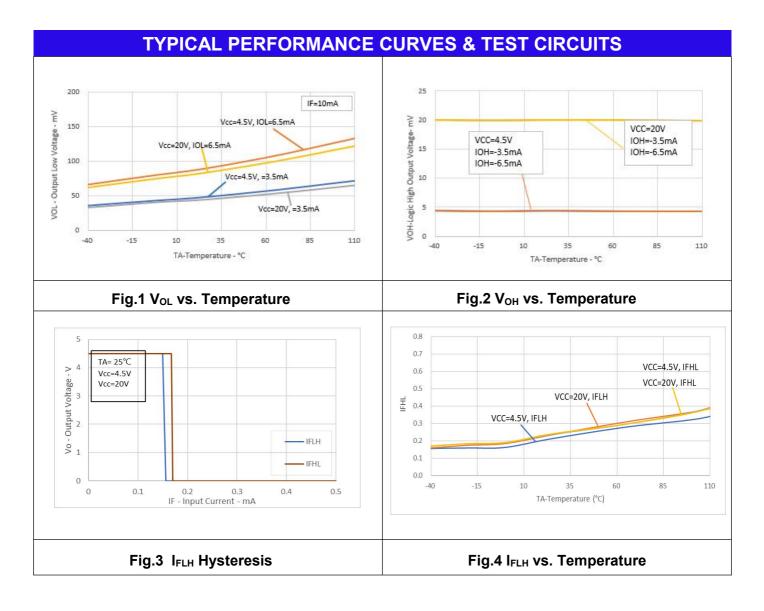


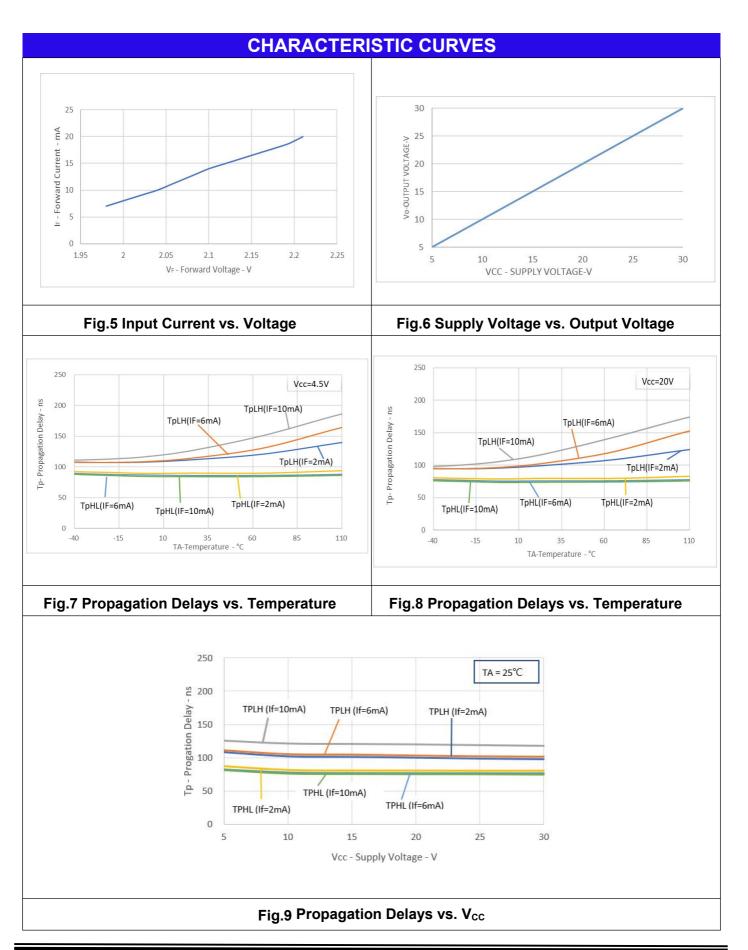
ISOLATION CHARACTERISTIC							
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITION	NOTE
Withstand Insulation Test Voltage	V _{ISO}	5000	-	_	V	RH≤40~60%, t=1min,T _A =25°C	1,2
Input-Output Resistance	R _{I-O}	-	10 ¹²	-	Ω	V _{I-O} =500V DC	1

All Typical values at TA = 25°C

Note 1: Device is considered a two terminal device: pins 1, 2, 3 are shorted together and pins 4, 5, 6 are shorted together.

Note 2: According to UL1577, each photocoupler is tested by applying an insulation test voltage 6000VRMS for one second. This test is performed before the 100% production test for partial discharge.







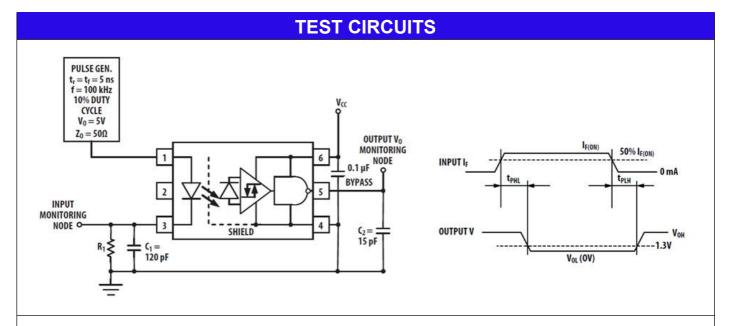


Fig.10 Test Circuit for tPLH、tPHL、tr and tf

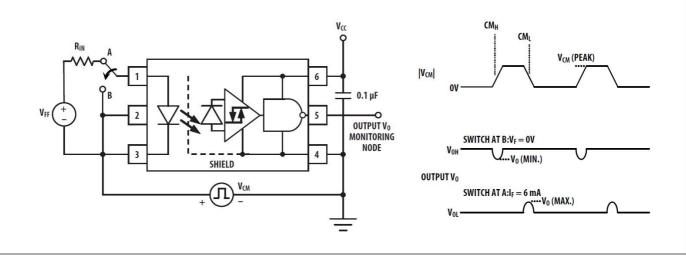


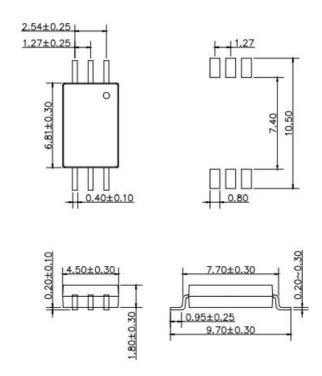
Fig.11 Common Mode Transient Immunity Test Circuit and Typical Waveforms



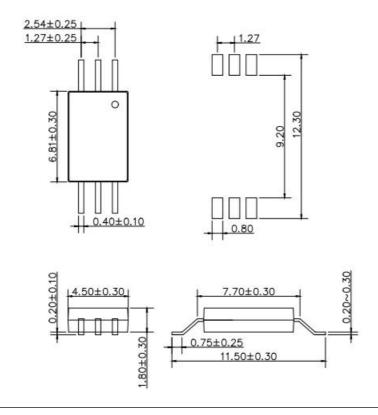
PACKAGE DIMENSIONS (Dimensions in mm unless otherwise stated)

Surface Mount Lead Forming

P type Dimension



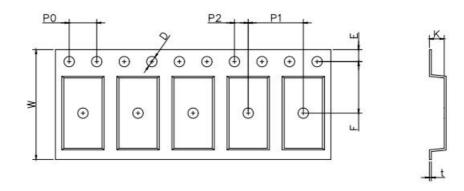
W type Dimension





TAPING DIMENSIONS (Dimensions in mm unless otherwise stated)

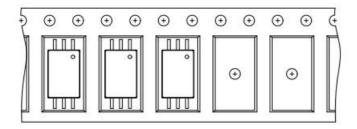
Taping Dimensions



Dimension Symbol	D	E	F	P0	P1	P2	t	W	K
P type Dimension (mm)	1.5±0.1	1.75±0.1	7.5±0.1	4.0±0.1	8.0±0.1	2.0±0.1	0.3±0.1	16.0±0.3	2.15±0.1
W type Dimension (mm)	1.5±0.1	1.75±0.1	11.5±0.1	4.0±0.1	8.0±0.1	2.0±0.1	0.3±0.1	24.0±0.3	2.52±0.1

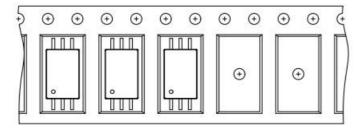
Tape & Reel Packing Specifications

Option T1





Option T2







ORDERING AND MARKING INFORMATION

MARKING INFORMATION



MP : Company Abbr.

H: High performance Photocoupler

481 : Part Number

P/W : Lead Form Option

V : VDE Identification(Option)

Y: Year date code

H : Factory identification mark

WW : 2-digit work week

ORDERING INFORMATION

MPH481(P/W)-VZ

MP- Company Abbr.

H – High performance Photocoupler

481 - Part Number

P/W – Lead Form Option(P-9mm Clearance or W-11mm Clearance)

V - VDE Option (V or None)

Z – Tape and Reel Option (T1/T2)

Packing Quantity

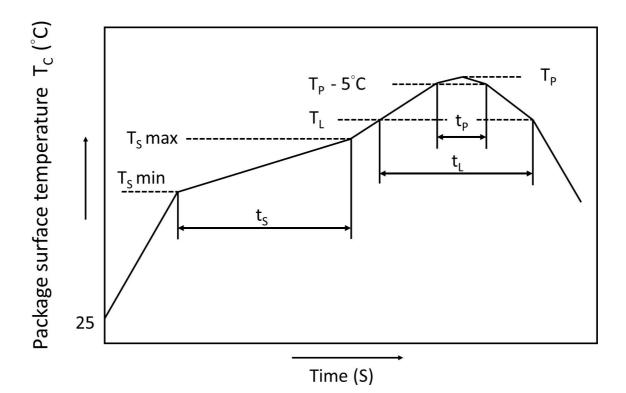
Option	Description	Quantity
P(T1)	Surface Mount Lead Forming – With Option 1 Taping	3000 Units/Reel
P(T2)	Surface Mount Lead Forming – With Option 2 Taping	3000 Units/Reel
W(T1)	Surface Mount Lead Forming – With Option 1 Taping	3000 Units/Reel
W(T2)	Surface Mount Lead Forming – With Option 2 Taping	3000 Units/Reel

REFLOW INFORMATION

REFLOW PROFILE

IR Reflow soldering

One time soldering reflow is recommended within the condition of temperature and time profile shown below. Do not solder more than three times.



	Symbol	Min.	Max.	Unit
Preheat temperature	Ts	150	200	°C
Preheat time	ts	60	120	S
Ramp-up rate (T∟to T _P)			3	°C/s
Liquidus temperature	TL	21	7	°C
Time above T∟	t∟	60	100	S
Peak Temperature	Тр		260	°C
Time during which T _C is between (T _P - 5) and T _P	t⊳		20	s
Ramp-down rate			6	°C/s



DISCLAIMER

- Our company is continually improving the quality, reliability, function and design. Our company reserves the right to make changes without further notices.
- The characteristic curves shown in this datasheet are representing typical performance which are not guaranteed.
- This product is not intended to be used for military, aircraft, automotive, medical, life sustaining or lifesaving applications or any other application which can result in human injury or death.
- Immerge unit's body in solder paste is not recommended.
- Discoloration might be occurred on the package surface after soldering, reflow or longtime use. It neither impacts the performance nor reliability.

Revision History

Version	Date	Subjects (major changes since last revision)				
1.0	2022-07-22	Datasheet Complete				